

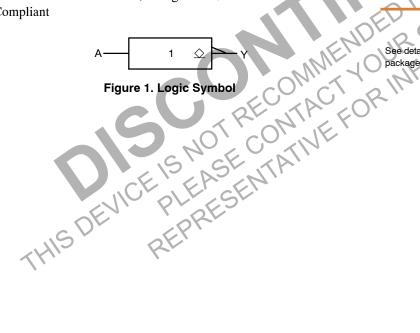
Single Inverter with Open Drain Output

NLV17SZ06

The NLV17SZ06 is a single inverter with open drain output in tiny footprint packages.

Features

- Designed for 1.65 V to 5.5 V V_{CC} Operation
- 2.1 ns t_{PD} at $V_{CC} = 5 \text{ V (typ)}$
- Input/Output Overvoltage Tolerant up to 5.5 V
- I_{OFF} Supports Partial Power Down Protection
- Source/Sink 24 mA at 3.0 V
- Available in SC-88A, SOT-553 and SOT-953
- Chip Complexity < 100 FETs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



MARKING DIAGRAMS



SC-88A CASE 419A





SOT-553 **XV5 SUFFIX CASE 463B**





SOT-953 P5 SUFFIX CASE 527AE



Specific Device Code = Date Code* M Pb-Free Package

(Note: Microdot may be in either location) Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 7 of this data sheet.

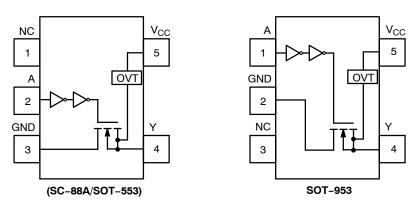


Figure 2. Pinout (Top View)

PIN ASSIGNMENT

(SC-88A/SOT-553)

Pin	Function
1	NC
2	А
3	GND
4	Y
5	V _{CC}

PIN ASSIGNMENT (SOT-953)

Pin	Function		Pin	Function	A Input
1	NC		1	Α	L (3)
2	А		2	GND	Н
3	GND		3	NC	IEN.
4	Y		4	Y	2
5	V _{CC}		5	V _{CC}	EO, WIN
THIS	DEVICE PI	NEPPR	OF RECONSESSENTATION OF THE SENTATION OF	MENDED MENDED ACTORIN	FORMATION ROBINSTION

FUNCTION TABLE

A Input	Y Output	
L) z	
H	L	

MAXIMUM RATINGS

Symbol	Characteristics	Value	Unit	
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	DC Input Voltage		-0.5 to +7.0	V
V _{OUT}	DC Output Voltage Active-Mode (Hig Tri-State Power-Down Mo	Mode (Note 1)	-0.5 to V _{CC} + 0.5 -0.5 to +7.0 -0.5 to +7.0	V
	DC Output Voltage (NL17SZ06P5T5G	-L22088 Only)	-0.5 to V _{CC} + 0.5	
I _{IK}	DC Input Diode Current	V _{IN} < GND	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < GND	-50	mA
	DC Output Diode Current (NL17SZ06P5T5G	-L22088 Only)	±50	
l _{out}	DC Output Source/Sink Current		±50	mA
I _{CC} or I _{GND}	DC Supply Current per Supply Pin or Ground Pin		±100	mA
T _{STG}	Storage Temperature Range		-65 to +150	7 ∘c
T_L	Lead Temperature, 1 mm from Case for 10 secs		260	°C
T_J	Junction Temperature Under Bias		+150	°C
θЈΑ	Thermal Resistance (Note 2)	SC-88A SOT-553 SOT-953	377 324 254	°C/W
P _D	Power Dissipation in Still Air	SC-88A SOT-553 SOT-953	332 386 491	mW
MSL	Moisture Sensitivity	0/20/	Level 1	=
F _R	Flammability Rating Oxygen	Index: 28 to 34	UL 94 V-0 @ 0.125 in	=
V _{ESD}	ESD Withstand Voltage (Note 3) Hum Charge	an Body Model d Device Model	2000 1000	V
I _{Latchup}	Latchup Performance (Note 4)	14	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri–stated.

Applicable to devices with duputs that may be the stated.
 Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
 HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
 Tested to EIA/JESD78 Class II.

THIS DEW

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics			Max	Unit
V _{CC}	Positive DC Supply Voltage		1.65	5.5	V
V _{IN}	DC Input Voltage		0	5.5	V
V _{OUT}	DC Output Voltage	Active–Mode (High or Low State) Tri–State Mode (Note 1) Power–Down Mode ($V_{CC} = 0 \text{ V}$)	0 0 0	V _{CC} 5.5 5.5	V
	DC Output Voltage	(NL17SZ06P5T5G-L22088 Only)	0	V _{CC}	
T _A	Operating Temperature Range		-55	+125	°C
t _r , t _f	Input Rise and Fall Time	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0	100 20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

			V _{CC}	T	A = 25°	С	–55°C ≤ T	A ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
V _{IH}	High-Level Input Volt	age	1.65 to 1.95	0.75 x V _{CC}	-	-	0.75 x V _{CC}	-	V
			2.3 to 5.5	0.70 x V _{CC}	1	- 1/	0.70 x V _{CC}	-	
V_{IL}	Low-Level Input Volta	age	1.65 to 1.95	-	-	0.25 x V _{CC}	-	0.25 x V _{CC}	٧
			2.3 to 5.5	-)	0.30 x V _{CC}		0.30 x V _{CC}	
V _{OL}	Low-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OL} = 100 \mu\text{A} \\ &I_{OL} = 4 \text{ mA} \\ &I_{OL} = 8 \text{ mA} \\ &I_{OL} = 12 \text{ mA} \\ &I_{OL} = 16 \text{ mA} \\ &I_{OL} = 24 \text{ mA} \\ &I_{OL} = 32 \text{ mA} \end{aligned}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	MENC MENC	0.08 0.2 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55	A	0.1 0.24 0.3 0.4 0.4 0.55	V
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V or GND	1.65 to 5.5	IE-FO	-	±0.1	-	±1.0	μΑ
l _{OZ}	3-State Output Leakage Current	V _{OUT} = 0 V to 5.5 V	1.65 to 5.5	_	-	±0.5	-	±5.0	μΑ
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5 V or V _{OUT} = 5.5 V	0	-	_	1.0	ı	10	μΑ
	Power Off Leakage Current (NL17SZ06P5T5G- L22088 Only)	V _{IN} = 5.5	0		_	1.0		10	μΑ
I _{CC}	Quiescent Supply Current	V _{IN} = V _{CC} or GND	5.5	-	-	1.0	-	10	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

			V _{CC}	T,	_A = 25°	С	-55°C ≤ T	_A ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
t _{PZL}	Propagation Delay,		1.65 to 1.95	-	6.0	9.0	_	9.5	ns
	A to Y (Figures 3 and 4)		2.3 to 2.7	-	3.6	6.1	-	6.5	
			3.0 to 3.6	-	2.7	5.6	=	6.0	
			4.5 to 5.5	-	2.1	4.4	=	4.8	
t _{PLZ}	Propagation Delay,		1.65 to 1.95	-	4.0	9.0	=	9.5	ns
	A to Y (Figures 3 and 4)		2.3 to 2.7	-	2.8	6.1	-	6.5	
			3.0 to 3.6	_	2.5	5.6	_	6.0	
			4.5 to 5.5	_	2.2	4.4	_	4.8	

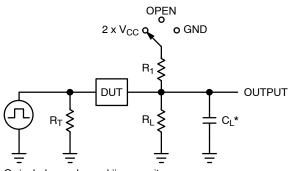
CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Units
C _{IN}	Input Capacitance	V _{CC} = 5.5 V, V _{IN} = 0 V or V _{CC}	2.5	pF
C _{OUT}	Output Capacitance	$V_{CC} = 5.5 \text{ V}, V_{IN} = 0 \text{ V or } V_{CC}$	2.5	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	10 MHz, V_{CC} = 3.3 V, V_{IN} = 0 V or V_{CC} 10 MHz, V_{CC} = 5.5 V, V_{IN} = 0 V or V_{CC}	9 11	pF

⁽Note 5)

10 MHz, $V_{CC} = 5.5 \text{ V/V}_{IN} = 0 \text{ V or } V_{OC}$ 11

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \cdot V_{CC} \cdot f_{irt} + I_{CC} \cdot C_{PD}$ is used to determine the no-load dynamic power consumption; $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_{irt} + I_{CC} \cdot V_{CC}$



Test	Switch Position	C _L , pF	R_L, Ω	R ₁ , Ω	
t _{PLH} / t _{PHL}	Open	See AC Characteristics Table			
t _{PLZ} / t _{PZL}	2 x V _{CC}	50	500	500	
t _{PHZ} / t _{PZH}	GND	50	500	500	

X = Don't Care

C_L includes probe and jig capacitance

 R_T is Z_{OUT} of pulse generator (typically 50 Ω) f=1 MHz

Figure 3. Test Circuit

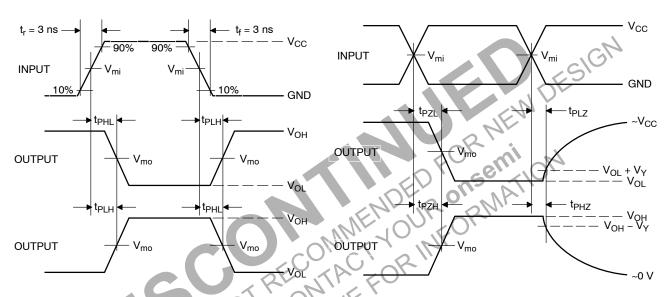


Figure 4. Switching Waveforms

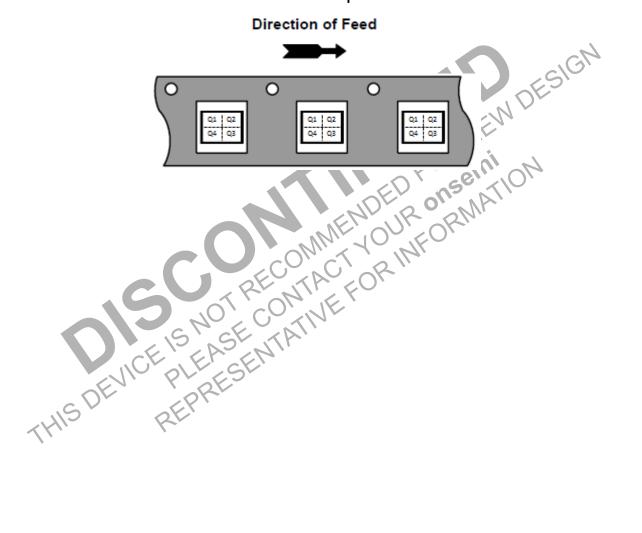
	INCHAIR CE	V _{mo}	, V	
V _{CC} , V	V _{mi} , V	t _{PLH} , t _{PHL}	t_{PZL} , t_{PLZ} , t_{PZH} , t_{PHZ}	V _Y , V
1.65 to 1.95	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.15
2.3 to 2.7	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.15
3.0 to 3.6	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.3
4.5 to 5.5	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.3

DEVICE ORDERING INFORMATION

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping [†]
NLV17SZ06DFT2G*	SC-88A	LF	Q4	3000 / Tape & Reel
NL17SZ06XV5T2G-L22087	SOT-553	LF	Q4	4000 / Tape & Reel
NL17SZ06P5T5G-L22088	SOT-953	A (Rotated 180°)	Q2	8000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Pin 1 Orientation in Tape and Reel



^{*}NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.





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SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

DATE 11 APR 2023

NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- 419A-01 DBSDLETE, NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

DIM	MILLIMETERS				
INITU	MIN.	N□M.	MAX.		
А	0.80	0.95	1.10		
A1			0.10		
A3	0.20 REF				
b	0.10	0.20	0.30		
C	0.10		0.25		
D	1.80	2.00	2,20		
Е	2.00	2.10	2.20		
E1	1.15	1.25	1.35		
е	0.65 BSC				
L	0.10	0.15	0.30		

5X b

→ 0.2 M B M

- PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

	L 			
<u> </u>	0.50	5		

RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

5. COLLECTOR

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. CATHODE
2. EMITTER	2. EMITTER	2. N/C	2. DRAIN 1/2	2. COMMON ANODE
3. BASE	3. BASE	3. ANODE 2	SOURCE 1	3. CATHODE 2
4. COLLECTOR	COLLECTOR	CATHODE 2	4. GATE 1	4. CATHODE 3
COLLECTOR	CATHODE	CATHODE 1	5. GATE 2	5. CATHODE 4
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	Note: Please refer to datasheet for
PIN 1. EMITTER 2	PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE	atula callout. If atula tupa is not called
2. BASE 2	2. EMITTER	2. COLLECTOR	2. CATHODE	style callout. If style type is not called
EMITTER 1	3. BASE	3. N/C	3. ANODE	out in the datasheet refer to the device
4. COLLECTOR	COLLECTOR	4. BASE	4. ANODE	datasheet pinout or pin assignment.
COLLECTOR 2/BASE 1	5. COLLECTOR	5. EMITTER	5. ANODE	datasheet pinout of pin assignment.

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5. EMITTER

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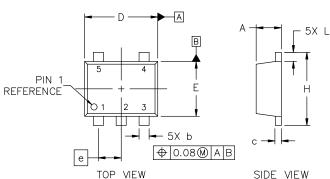
5. COLLECTOR 2/BASE 1





SOT-553-5 1.60x1.20x0.55, 0.50P CASE 463B ISSUE D

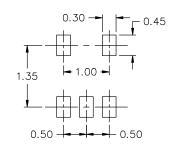
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NOTES:

- . DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- . ALL DIMENSION ARE IN MILLIMETERS.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	MILLIMETERS				
DIIVI	MIN.	NOM.	MAX.		
А	0.50	0.55	0.60		
Ь	0.17	0.22	0.27 0.18		
O	0.08	0.13			
О	1.55	1.60	1.65		
E	1.15	1.20	1.25		
е	0.50 BSC				
H 1.55		1.60	1.65		
L	L 0.10		0.30		



RECOMMENDED MOUNTING FOOTPRINT*

* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XX = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 1 5. COLLECTOR 2/BASE 1	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	

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DESCRIPTION: SOT-553-5 1.60x1.20x0.55, 0.50P PAGE 1 OF 1

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